Other MOS LSIs

MN63154 EEPROM for IC Cards

Overview

The MN63154 is an EEPROM for use in IC cards. It features security features and an address specification system using opcode input.

Low cost combined with high security makes the chips ideal for use in prepaid cards and other types of IC cards.

Features

- Easy-to-use control system
- Address specification system using opcode input over a 3-wire interface (CLK, I/O, and RST)
- Automatic erasing and writing using a single 5 volt power supply
- Flexible memory-layout
 - The memory is divided into 11 areas. Six areas containing 500 bytes are freely usable.
- Advanced security features
 - Verification of IC card authenticity

The IC passes entered data through a random number generator circuit on its way to output to provide a check of card validity.

• Protection against malicious experimentation

Four or more unsuccessful attempts to access the IC card render it permanently unusable.

• Protection of individual memory areas on the card

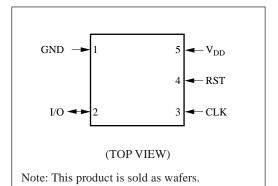
Read or write access to a memory area requires matches for both security and condition codes. There is also a condition code for permanently disabling re-write.

- Mixed configuration of EPROM and EEPROM Individual areas consist of EPROM or EEPROM.
- High reliability
 - Write cycles: 10,000 times
 - Data storage interval: 10 years

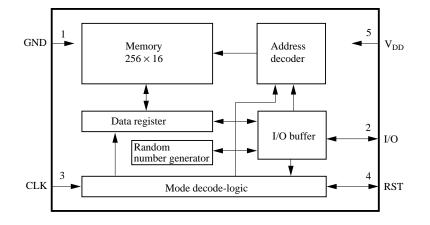
Applications

• IC cards

Pad Assignment



Block Diagram



Pin Descriptions

Pin No.	Symbol	Pin Name	I/O	
1	GND	Ground	Ι	
2	I/O	Data I/O	I/O	
3	CLK	Clock	Ι	
4	RST	Reset	Ι	
5	V _{DD}	Power supply	Ι	

Electrical Characteristics

 V_{CC} =4.5 to 5.5V, Ta=-10°C to +70°C

Parameter	Symbol	Test Conditions	min	max	Unit
Power supply voltage	V _{CC}		4.5	5.5	V
"L" level input leakage current	I _{LIL}		-10	10	μΑ
"H" level input leakage current	I _{LIH}		-10	10	μΑ
V _{CC} power supply current	I _{CC}	V _{CC} =5.5V		5.45	mA
(during operation)		CLK=800kHz		5.45	IIIA
V _{CC} power supply current	I _{SB}	CLK="L"		0.19	
(during standby)		I/O="H"		0.18	mA

Notes

1: I/O pins use N-channel, open drain configuration.

2: Input voltages, output voltages, and other items not listed above conform to ISO/IEC 7816-3.

Function Descriptions

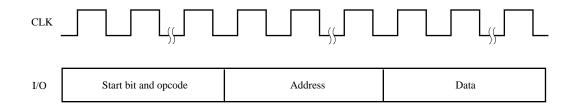
Orders	Start bit	Operation code	Address	Data	Contents
READ	0	10	A_8 , A_7 to A_0	D_0 , D_1 to D_{31}	Read
WRITE	0	01	A_8 , A_7 to A_0	D_0 , D_1 to D_{15}	Write
VERIFY	0	11	000001010	D ₀ , D ₁ to D ₃₁	Verify code
RNGEN	0	00	000001010	D_0 , D_1 to D_{31}	Verify code, generate
				D_{O0} , D_{O1} to D_{O31}	random number
RESET	0	11	111111111		Reset
EWEN	0	00	1xxxxxxxx		Enable write

Note: x means "don't care".

Area	Contents	Number of Bits	Memory Type
А	Chip manufacturer's code	16	EPROM
В	Card manufacturer's code	16	EPROM
С	Spare area 1	32	EPROM
D	Spare area 2	16	EEPROM
Е	Spare area 3	48	EPROM
F	Spare area 4	16	EEPROM
G	Security code	32	EEPROM
Н	Error counter	16	EEPROM
I1	Condition code 1	8	EPROM
I2	Condition code 2	8	EEPROM
J	Application area 1	1952	EEPROM
K	Application area 2	1936	EEPROM

Memory Layout

Timing Chart



Note: This product is sold as wafers.